Alcatel 1915 LMI 1.55 µm WDM Laser Module 2.5 Gb/s Direct Modulation 10mW



Description

This laser module contains an Alcatel SLMQW DFB laser with 25 Ω impedance matching designed for use in Wavelength Division Multiplexed (WDM) systems, high power direct modulation operations up to 2.5 Gbit/s. The module incorporates a thermoelectric cooler, precision thermistor, and optical isolator for stable operation under all conditions.

Features

- 10 mW output power
- Low dispersion penalty
- Optimized for direct modulation at 2.5 Gbit/s
- Wavelength selection according to ITU-T G.692 from 1528.77 nm to 1570.42 nm
- High extinction Ratio

- 100 GHz spacing available
- Internal optical isolator
- 25 Ω RF impedance matching and DC bias RF filtering
- Industry standard hermetic 14-pin butterfly package
- InGaAsP Distributed FeedBack SLMQW (DFB) laser

Applications

- EDFA free long span STM-16 and OC-48 DWDM transmission systems
- High-speed DWDM
 Metropolitan Area Networks
- Saturation Laser for WDM EDFA
- Instrumentation.

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Electro-Opto Characteristics

Table 1

Parameter	Sym	Conditions	Min	Тур.	Max	Units
Fiber-Coupled Peak Power	P _{peak}	@Twave	10		-	mW
Threshold current	İ _{TH}	@Twave	3		25	mA
External Diff. Efficiency	η	@Twave	0.120			W/A
Laser forward voltage	V_{F}	@P _{Peak} = 10 mW ; pin 11 & 3	-		2.5	V
Modulation current	I _F	@P _{Peak} = 10 mW ; pin 11 & 3 Note 1	-	60	80	mA
Serial resistance	R_{S}	P _{peak} =10mW; pin 11 &12	22		27	Ω
Δ (Emitted -Target	Δλε	@Twave	-0.1		+0.1	nm
Wavelength)		See Table 4 for $\Delta_{ ext{target}}$				
Emission wavelength	λ	See table 4	1529		1570	nm
Side mode suppression	SMSR	@Twave ; Note 2	40		-	dB
Photodiode Current	I _{PD}	V = -5 V, @Pmean, Note 5	30		300	μΑ
Photodiode Dark Current	I _D	V = -5 V			0.1	μΑ
Photodiode Capacitance	C _M	V = -5V @ 1MHz			15	рF
Thermistor resistance	R _{TH}		9.7		10.3	kΩ
Coefficient of RTH			-3		-5	%/°K
Emitted λ drift vs I _F	$\Delta \lambda / I$		-	3	6	pm/mA
Emitted λ drift vs Twave	Δλ/ΔTw	20°C ≤ Tsubmount ≤ 35°C	80		100	pm/°C
Emitted λ drift vs Tcase	Δλ/ΔΤς	$0^{\circ}C \le Tc \le 70^{\circ}C$	-		0.5	pm/°C
Relative Intensity Noise	RIN	100 MHz to 3 GHz @Pmean			-140	dB/Hz
Dispersion Penalty	ΔS	D = 1800 ps/nm, Note 2	-		2	dB
Linearity (kink) Note 3	ΔΡ/ΔΙ	$0.2 \text{ mW} \le P_{Peak} \le 10 \text{ mW}$			15	%
Optical Isolation	OI	$0^{\circ}C \le T_{c} \le 70^{\circ}C$	30		-	dB
Tracking Error Note 4	Q	@10 mW PPeak			10	%
Extinction ratio	ER	2.5Gb/s, D=1800ps/nm PRBS 2 ²³⁻¹	10			dB
Case Operating Temperature	Тс		0		70	°C
Tsubmount	Ts		20		35	°C
TEC current EOL	I ₊	@I(10mW), Ts = 20° C, Tc = 70° C	-		1.2	Α
TEC voltage EOL	V _t	@I(10mW), Ts = 20° C, Tc = 70° C	-		2.4	V

Note 1: Modulation current = $P_{Peak} / \eta * [(1 - ER) / (1 + ER)]$ End Of Life criteria; delta IF/IF = 20% or delta IM / IM = 20% or delta ITH / ITH = 20%

Note 2 : 2.488 Gb/s, Pmean = 5 mW, BER = 10^{-10} , ER = $10\pm1\%$, NRZ line code

Note 3: relative deviation of dP / dl between 2 consecutive measurement points

Note 4: $Q = Max \{ | [P(70 C) - P(25 C)] / P(25 C) | ; | [P(0 C) - P(25 C)] / P(25 C) | \}$

measurements @ 0 & 70°C are with I_F set at constant I_F (25 C)

Note 5 : Pmean=Peak/2

Definitions

Twave

Twave is the submount temperature at which the laser emission wavelength reaches the target wavelength with an accuracy of better than: $\lambda_{\text{target}} \pm 0.1 \text{nm}$.

This temperature is calculated during manufacturing according to:

Twave = 25° C + $(1/C)^{*}(\lambda_{target} - \lambda_{25^{\circ}C})$, where C is the laser wavelength drift with temperature (in nm/°C).

Emitted wavelength drift vs Tcase

Absolute value of maximum emitted wavelength deviation per unit of case temperature (°C) when Tcase varies from min to max operating conditions.

Wavelength is stabilized through the thermal regulation of the laser chip based on the thermistor reading.

Emitted wavelength drift vs Laser Current

Maximum emitted wavelength deviation per unit of laser current (mA) when the DC output power varies around P_{mean} .

Absolute maximum ratings

Exposing the device to stresses above those listed in absolute maximum rating could cause permanent damage.

Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Environmental

Table 2

Parameters	Min	Max	Unit
Storage temperature	- 40	85	°C
Operating temperature	-10	70	°C
Soldering temperature (3 seconds maximum)		350	°C
Axial force on fiber (10 seconds max.)		10	Ν
Fiber bend radius	30		mm
ESD (1) applied on PIN detector (Pin 4&5)		100	V
ESD (1) on other Pin		2000	V

⁽¹⁾ Human body model

Electro-optic

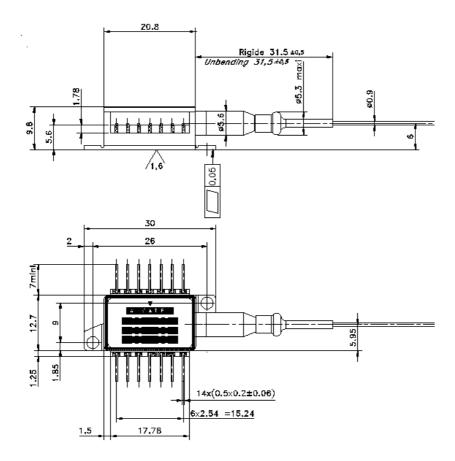
Table 3

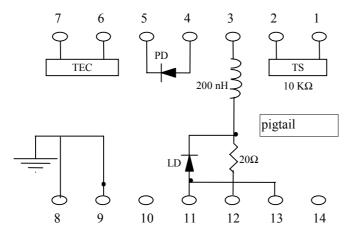
Parameters	Min	Max	Unit
Laser forward current		150	mA
Laser reverse voltage		2	V
Photodiode forward current		1	mA
Photodiode reverse voltage		20	V
Thermistor Voltage		9	V
Thermistor Current		250	μΑ
TEC Voltage		2.8	V
TEC Current		1.4	Α
Packing Mounting Torque		0.2	N.m



Mechanical details

Note: all dimensions in mm





Pin out

N°	Description	N°	Description
1	Thermistor	8	Case Ground
2	Thermistor	9	Case Ground
3	Laser DC bias (-)	10	Not Connected
4	Photodetector Anode (-)	11	RF common (+)
5	Photodetector Cathode (+)	12	Laser Modulation (-)
6	TEC (+)	13	RF common (+)
7	TEC (-)	14	Not Connected



Marking, packing and deliverable data

Device marking

Each device includes the following information as a minimum:

- 1. Alcatel logo
- 2. Product family name: A 1915 LMI
- 3. Product code: 3CN 00466 XX
- 4. Serial number

Packing

Each device is individually packed in an antistatic container and in such a manner as to prevent damage in transit.

The packaging shall include the following information:

- 1. Alcatel logo
- 2. Product family name: A 1915 LMI
- 3. Product code: 3CN 00466 XX
- 4. Serial number
- 5. Hazard warning label (ESD)
- 6. Laser Safety Class Label

Deliverable data

The following data shall be supplied with each device:

- 1. L(I)/V(I) curves @ Tcase/ Tsubmount = 25°C/25°C
- 2. TEC current and voltage @ Tcase/Tsubmount=25°C/70°C, P=10mW
- 3. Values of Twave and Thermistor @ Tsubmount =Twave
- 4. Values of laser forward current, monitoring photocurrent, laser threshold current and external differential efficiency @ Tsubmount =Twave
- 5. Peak wavelength at Tcase/Tchip=25°C and under modulation
- 6. Dispersion penalty

Product testing shall be carried out at a level that ensures conformity to the customer specification

Safety and handling

Safety and IEC.825 Classification

Take appropriate precautions to prevent undue exposure to naked eye.

This product is classified Class 3A Laser Product according to IEC.825

Handling

This product, in line with all similar devices, is sensitive to electrostatic discharge. Take precautions to prevent ESD; use wrist straps, grounded work surfaces and recognized anti-static techniques when handling the laser. Handle the laser module by its package only, never hold it by leads or pigtail.

For package mounting the following procedure should be carefully followed:

- 1. In order to achieve the ultimate thermal performance of the device, thermal paste can be usefully added on the support
- 2. Tighten screws up to 200 mN/m Do not exceed this mounting torque.
- Assure that the leads are aligned and in contact with appropriate contact pads.

Care should be taken to avoid supply transient and over voltage. Over voltage above the maximum specified in absolute maximum rating section (table3) may cause permanent damage to the device.







Ordering information

Alcatel 1915 LMI

Nominal power	Connector type	Part number
10 mW	FC/PC	3CN 00466 ##

defines the wavelength and the connector according to the following table .

Table 4

Table 4					
λ	THz	Connector	λ	THz	Connector
(1)		FC/PC			FC/PC
` '					
1500.77	10/10	DAA	1550.10	100.40	DI
1528,77	196,10	BM	1550,12	193,40	DT
1529,55	196,00	BP	1550,92	193,30	DV
1530,33	195,90	BR	1551,72	193,20	DX
1531,12	195,80	BT	1552,52	193,10	DZ
1531,90	195,70	BV	1553,33	193,00	EB
1532,68	195,60	BX	1554,12	192,90	ED
1533,47	195,50	BZ	1554,94	192,80	EF
1534,25	195,40	СВ	1555,75	192,70	EH
1535,04	195,30	CD	1556,55	192,60	EK
1535,82	195,20	CF	1557,36	192,50	EM
1536,61	195,10	CH	1558,17	192,40	EP
1537,40	195,00	CK	1558,98	192,30	ER
1538,19	194,90	CM	1559,79	192,20	ET
1538,98	194,80	СР	1560,61	192,10	EV
1539,77	194,70	CR	1561,42	192,00	EX
1540,56	194,60	CT	1562,23	191,90	EZ
1541,35	194,50	CV	1563,05	191,80	FB
1542,14	194,40	CX	1563,86	191,70	FD
1542,94	194,30	CZ	1564,68	191,60	FF
1543,73	194,20	DB	1565,49	191,50	FH
1544,53	194,10	DD	1566,31	191,40	FK
1545,32	194,00	DF	1567,13	191,30	FM
1546,12	193,90	DH	1567,95	191,25	FP
1546,92	193,80	DK	1568,77	191,20	FS
1547,72	193,70	DM	1569,59	191,15	FU
1548,51	193,60	DP	1570,42	191,10	FW
1549,32	193,50	DR	,	,	

(1) in vacuum

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Customized versions are available for large quantities.

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